## First-principles study of substrate effects on electronic and magnetic properties of lanthanide-based single-molecule magnets

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The current rate of technological evolution necessitates a greater understanding of lowdimensional materials and their physical properties. As a result of the search for improved nanoscale electronic devices, transition metal dichalcogenides have come into focus. These materials have been shown to have applications in tunneling field-effect transistor and Esaki diode devices. In doped molybdenum disulfide p-n junctions, band-to-band tunneling is the foremost contributing factor to Esaki diode behavior at low potential bias. Using the nonequilibrium Green's function approach and effective screening medium in the framework of density functional theory (NEGF +ESM+ DFT), we investigated MoS<sub>2</sub> mono- and bi-layer junctions. Esaki diode behavior and a negative differential resistance regime are observed in these systems. Analysis of partial density of states reveals that the current across the junction is due to interlayer band-to-band tunneling. Finally, we discuss edge effects and edge state termination.